



SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

NEC

These products are N-channel MOS Field Effect Transistors designed for high current switching applications.

<R> ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE	
NP84N055EHE-E1-AY Note1, 2				
NP84N055EHE-E2-AY Note1, 2			TO-263 (MP-25ZJ) typ. 1.4 g	
NP84N055KHE-E1-AY Note1	Pure Sn (Tin)	Tape 800 p/reel		
NP84N055KHE-E2-AY Note1			TO-263 (MP-25ZK) typ. 1.5 g	
NP84N055CHE-S12-AZ Note1, 2	Sn-Ag-Cu		TO-220 (MP-25) typ. 1.9 g	
NP84N055DHE-S12-AY Note1, 2		Tube 50 p/tube	TO-262 (MP-25 Fin Cut) typ. 1.8 g	
NP84N055MHE-S18-AY Note1	Pure Sn (Tin)		TO-220 (MP-25K) typ. 1.9 g	
NP84N055NHE-S18-AY Note1			TO-262 (MP-25SK) typ. 1.8 g	

Notes 1. Pb-free (This product does not contain Pb in the external electrode.)

2. Not for new design

FEATURES

- Channel temperature 175 degree rated
- Super low on-state resistance
- $R_{DS(on)} = 7.3 \text{ m}\Omega$ MAX. (V_{GS} = 10 V, I_D = 42 A)
- Low input capacitance
- Ciss = 4540 pF TYP.
- Built-in gate protection diode









(TO-263)



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The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGs = 0 V)	VDSS	55	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C) ^{Note1}	D(DC)	±84	А
Drain Current (pulse) Note2	D(pulse)	±336	А
Total Power Dissipation (T _A = 25° C)	Рт	1.8	W
Total Power Dissipation (Tc = 25° C)	Рт	200	W
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	–55 to +175	°C
Single Avalanche Current Note3	las	84/56/21	А
Single Avalanche Energy Note3	Eas	70/313/441	mJ

Notes 1. Calculated constant current according to MAX. allowable channel temperature.

2. PW \leq 10 μ s, Duty cycle \leq 1%

3. Starting T_{ch} = 25°C, V_{DD} = 28 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V (See Figure 4.)

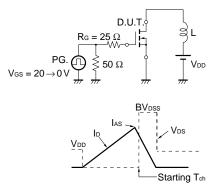
THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	0.75	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

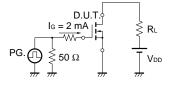
ELECTRICAL CHARACTERISTICS (T_A = 25°C)

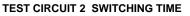
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 55 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	Igss	V_{GS} = ±20 V, V_{DS} = 0 V			±10	μA
Gate to Source Threshold Voltage	VGS(th)	V_{DS} = V_{GS} , ID = 250 μ A	2.0	3	4.0	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 42 A	20	44		S
Drain to Source On-state Resistance	RDS(on)	V _{GS} = 10 V, I _D = 42 A		5.8	7.3	mΩ
Input Capacitance	Ciss	V _{DS} = 25 V,		4540	6810	pF
Output Capacitance	Coss	V _{GS} = 0 V,		710	1070	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		340	620	pF
Turn-on Delay Time	td(on)	V _{DD} = 28 V, I _D = 42 A,		37	81	ns
Rise Time	tr	V _{GS} = 10 V,		22	54	ns
Turn-off Delay Time	td(off)	R _G = 1 Ω		76	150	ns
Fall Time	tr			22	56	ns
Total Gate Charge	QG	V _{DD} = 44 V,		88	130	nC
Gate to Source Charge	Q _{GS}	V _{GS} = 10 V,		22		nC
Gate to Drain Charge	Qgd	I _D = 84 A		31		nC
Body Diode Forward Voltage	V _{F(S-D)}	IF = 84 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 84 A, VGS = 0 V,		49		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		78		nC

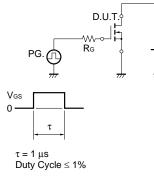
TEST CIRCUIT 1 AVALANCHE CAPABILITY

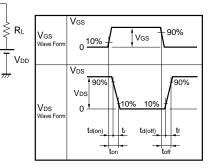


TEST CIRCUIT 3 GATE CHARGE

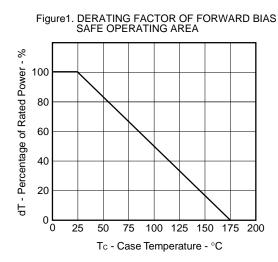


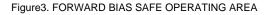


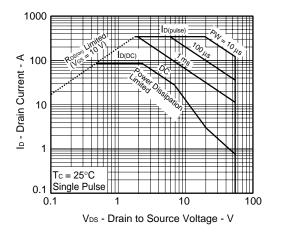




TYPICAL CHARACTERISTICS (T_A = 25°C)







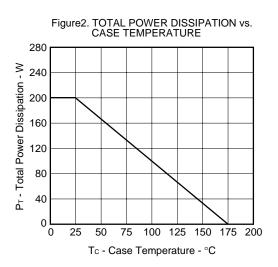
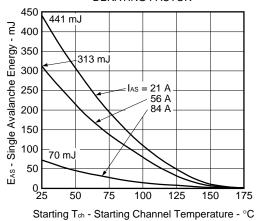


Figure4. SINGLE AVALANCHE ENERGY DERATING FACTOR





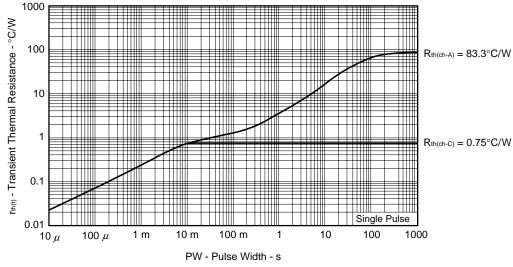


Figure6. FORWARD TRANSFER CHARACTERISTICS

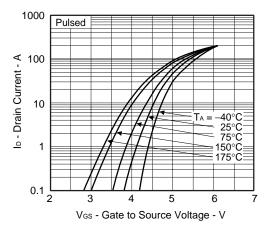
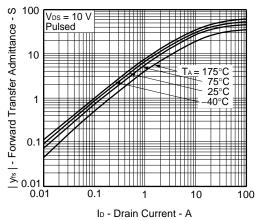
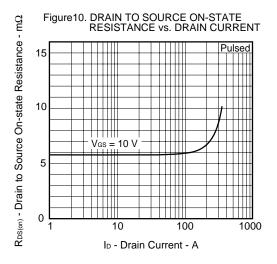
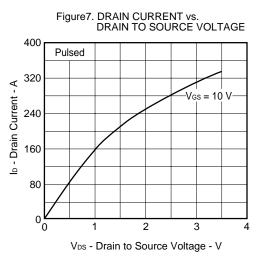
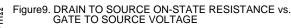


Figure8. FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT









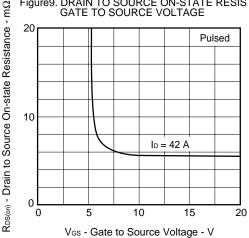
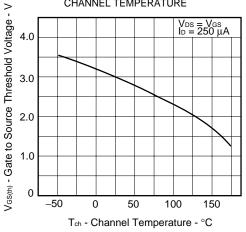
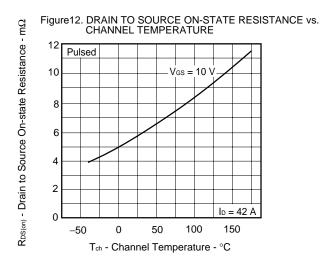
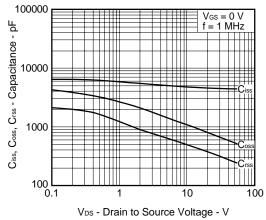


Figure11. GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE

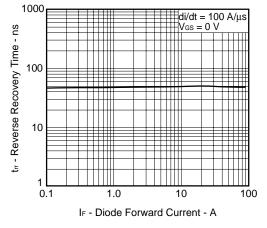












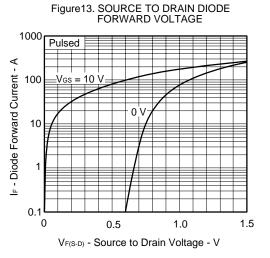
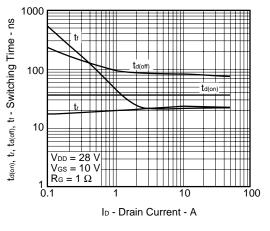
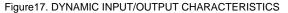
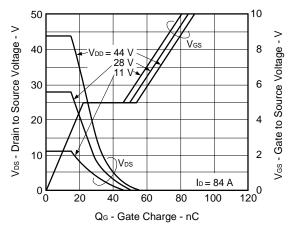


Figure 15. SWITCHING CHARACTERISTICS

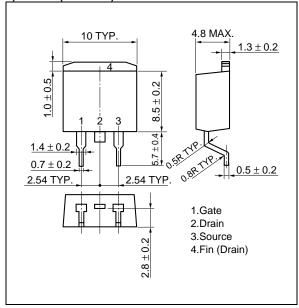


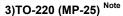


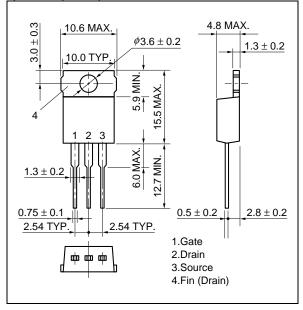


<R> PACKAGE DRAWINGS (Unit: mm)

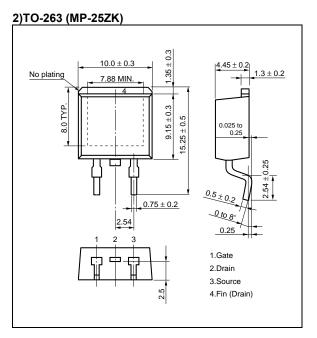
1)TO-263 (MP-25ZJ) Note



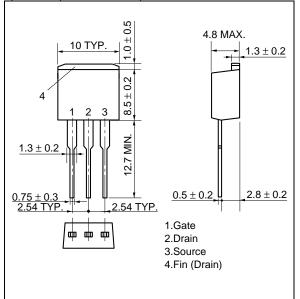


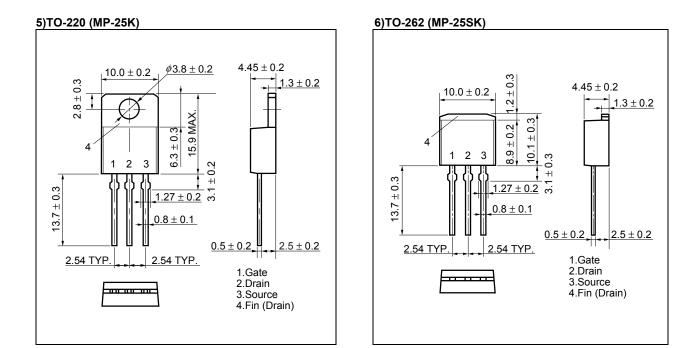


Note Not for new design

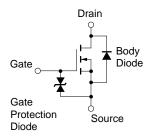


4)TO-262 (MP-25 Fin Cut) Note





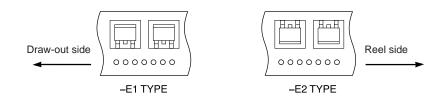
EQUIVALENT CIRCUIT



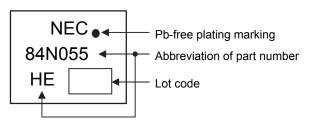
Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

<R> TAPE INFORMATION

There are two types (-E1, -E2) of taping depending on the direction of the device.



<R> MARKING INFORMATION



<R> RECOMMENDED SOLDERING CONDITIONS

These products should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

Soldering Method	Soldering Conditions	Recommended Condition Symbol	
Infrared reflow	Maximum temperature (Package's surface temperature): 260°C or below		
MP-25ZJ, MP-25ZK	Time at maximum temperature: 10 seconds or less		
	Time of temperature higher than 220°C: 60 seconds or less	IR60-00-3	
	Preheating time at 160 to 180°C: 60 to 120 seconds		
	Maximum number of reflow processes: 3 times		
	Maximum chlorine content of rosin flux (percentage mass): 0.2% or less		
Wave soldering	Maximum temperature (Solder temperature): 260°C or below		
MP-25, MP-25K, MP-25SK,	Time: 10 seconds or less	THDWS	
MP-25 Fin Cut	Maximum chlorine content of rosin flux: 0.2% (wt.) or less		
Partial heating	Maximum temperature (Pin temperature): 350°C or below		
MP-25ZJ, MP-25ZK,	Time (per side of the device): 3 seconds or less	P350	
MP-25K, MP-25SK	Maximum chlorine content of rosin flux: 0.2% (wt.) or less		
Partial heating	Maximum temperature (Pin temperature): 300°C or below		
MP-25, MP-25 Fin Cut	Time (per side of the device): 3 seconds or less	P300	
	Maximum chlorine content of rosin flux: 0.2% (wt.) or less		

Caution Do not use different soldering methods together (except for partial heating).

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